

Module 1

Syllabus: Principle and Application areas of power electronics, Power semiconductor devices, Types of power electronic circuits such as controlled rectifiers, Inverters, Dc to dc choppers, AC regulators.

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Module 1

Chapter 2: Thyristors

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Syllabus: Basic operation of silicon controlled rectifier, Static characteristics, Two transistor analogy, Dynamic characteristics, Firing circuits (R, RC, Ramp triggering using UJT). Self study topic: Other devices of Thyristor family.

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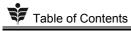
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Chapter 6 Single Phase Controlled Rectifiers

6-1 to 6-64

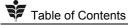
Syllabus Single phase half wave rectifiers, Full wave rectifiers (mid-point and bridge configuration) for R and R-L load, Freewheel diode, Rectification and inversion mode of single phase fully controlled rectifier, Single phase dual converter, Single phase PWM rectifier, Basic working principle and applications.

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Chapter 8 : Single Phase Inverters

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Syllabus: Classification based on source and Power level, Single phase bridge Inverters (VSI), Performance parameters, Voltage control of single phase inverters- PWM techniques-Single PWM, Multiple PWM, Sinusoidal PWM, Basics of Space vector modulation, Single phase current source inverters (CSI), Comparison of VSI and CSI.

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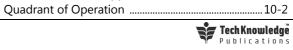


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Chapter 11: Auxiliary circuits

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11-1 to 11-16

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